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TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT Docket No. 3816.06-C1 (Under 37 CFR 1.97(b) or 1.97(c)) In Re Application Of: Raanan Y. ZEHAVI et al. Confirmation No. Customer No. Group Art Unit Application No. Filing Date Examiner 22337 2818 6952 unknown 10/829,641 04/22/04 Title: SILICON FIXTURE SUPPORTING SILICON WAFERS DURING HIGH TEMPERTURE **PROCESSING** Address to: JUL 2 1 2004 Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 37 CFR 1.97(b) The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114. 37 CFR 1.97(c) The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of: ☐ the statement specified in 37 CFR 1.97(e); OR ☐ the fee set forth in 37 CFR 1.17(p).

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT Docket No. (Under 37 CFR 1.97(b) or 1.97(c)) 3816.06-C1 In Re Application: Raanan Y. ZEHAVI et al. Customer No. Group Art Unit Confirmation No. Examiner Application No. Filing Date 22337 2818 6952 unknown 04/22/04 10/829,641 SILICON FIXTURE SUPPORTING SILICON WAFERS DURING HIGH TEMPERTURE Payment of Fee (Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p)) is attached. A check in the amount of ☑ The Director is hereby authorized to charge and credit Deposit Account No. 50-0636 as described below. Charge the amount of XCredit any overpayment. Charge any additional fee required. Certificate of Transmission by Facsimile* Certificate of Mailing by First Class Mail I certify that this document and fee is being deposited on I certify that this document and authorization to charge deposit with the U.S. Postal Service as first class account is being facsimile transmitted to the United States July 19, 2004 mail under 37 C.F.R. 1.8 and is addressed to the Patent and Trademark Office (Fax. No. Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450. (Date) Signature of Person Mailing Correspondence Signature Ingrid C. Mallory Typed or Printed Name of Person Mailing Certificate Typed or Printed Name of Person Signing Certificate *This certificate may only be used if paying by deposit account. Dated: July 19, 2004 Charles S. Guenzer, Reg. No. 30,640 (650) 566-8040 Mailing Address: Law Offices of Charles Guenzer 2211 Park Bouelvard P.O. Box 60729 Palo Alto, CA 94306 CC:

U.S. Department of Commerce, Patent and Trademark Office						Docket No.: 3816.06-C1				
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*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate			
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·	AB	5,516,283	05/14/96	Schrems	432	241				
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	AO									
·	AP									
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	AR	anonymous, "Epi-I	I advanced W	afer," MEMC Appplication	ons Note, AE-0	03, March 2000	, pp. 1-4			
	AS	anonymous, "Thin	epi layers sho	own to improve gate oxide	integrity perfor	mance," MEMO	C, date unknown, 1	.p		
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